

UNISONIC TECHNOLOGIES CO., LTD

UTT4425 Preliminary Power MOSFET

P-CHANNEL ENHANCEMENT MODE POWER MOSFET

DESCRIPTION

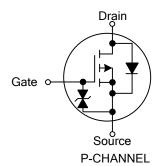
The UTC UTT4425 is a P-channel enhancement mode power MOSFET using UTC's advanced trench technology to provide customers with a minimum on-state resistance and extremal low gate charge with a 25V gate rating.

The UTC UTT4425 is ESD protected and it is universally applied in PWM or used as a load switch.

FEATURES

- * V_{DS(V)}= -30V
- * I_D=-14A, (V_{GS}= -20V)
- * $R_{DS(ON)}$ < 10m Ω @(V_{GS} = -20V) $R_{DS(ON)} < 11 m\Omega @(V_{GS} = -10V)$

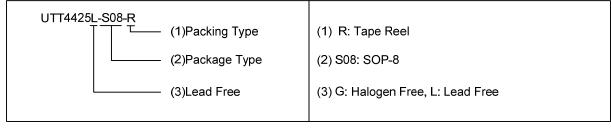
SYMBOL

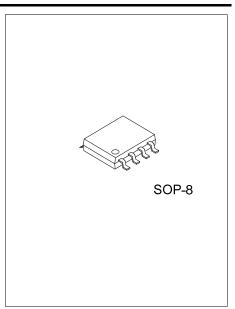


ORDERING INFORMATION

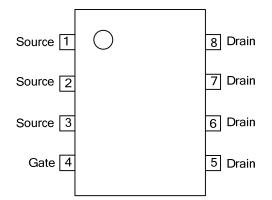
Ordering	Number	Daakaga	Packing	
Lead Free	Halogen Free	Package		
UTT4425L-S08-R	UTT4425G-S08-R	SOP-8	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source





■ PIN CONFIGURATION



■ ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

PARAMETER			SYMBOL	RATINGS	UNIT	
Drain-Source Voltage			V _{DSS}	-30	V	
Gate-Source Voltage			V_{GSS}	±25		
Drain Current	Continuous	T _A = 25°C		-14		
	(Note 2)	T _A = 70°C	I _D	-11	Α	
	Pulsed (Note 3)		I _{DM}	-50		
Dower Dissinction (Note 2)		T _A = 25°C	Б	3.1	W	
Power Dissipation (Note 2)		T _A = 70°C	P _D	2		
Junction Temperature			TJ	+150	°C	
Storage Temperature			T _{STG}	-55~+150	°C	

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note 2)	θ_{JA}	75	°C/W

- Note: 1 Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
 - 2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in^2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The value in any given application depends on the user's specific board design. The current rating is based on the t \leq 10s thermal resistance rating.
 - 3. Repetitive rating, pulse width limited by junction temperature.

■ ELECTRICAL CHARACTERISTICS (T」=25°C)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0 V, I _D =-250μA	-30			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =-30V, V _{GS} =0 V			-100	nA
			V _{DS} =-30V,V _{GS} =0V, T _J =55°C			-500	
Gate- Source Leakage Current	Forward	I _{GSS}	V _{GS} =+20V, V _{DS} =0V			+1	
	Reverse		V _{GS} =-20V, V _{DS} =0V			-1	
	Forward		V _{GS} =+25V, V _{DS} =0V			+10	μA
	Reverse		V _{GS} =-25V, V _{DS} =0V			-10	
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	-2	-2.5	-3.5	V
			V _{GS} =-20V, I _D =-14A		7.7	10	mΩ
Drain-Source On-State Resistance	е	R _{DS(ON)}	V _{GS} =-20V,I _D =-14A,T _J =125°C		11	13.5	mΩ
			V _{GS} =-10V, I _D =-14A		8.8	11	mΩ
DYNAMIC PARAMETERS							
Input Capacitance	Capacitance C _{ISS}		V 00.V V 0V		3800		pF
Output Capacitance		Coss	V _{DS} =-20 V, V _{GS} =0V, f=1MHz		560		
Reverse Transfer Capacitance		C _{RSS}			350		
Gate Resistance		Rg	V _{DS} =0V, V _{GS} =0V, f=1MHz		7.5		Ω
SWITCHING PARAMETERS							
Total Gate Charge		Q_G	V 00V V 40V		63		nC
Gate Source Charge		Q_GS	V _{DS} =-20V, V _{GS} =-10V,		14.1		
Gate Drain Charge		Q_GD	I _D =-14A (Note 1 ,2)		16.1		
Turn-ON Delay Time		t _{D(ON)}	V 00V V 40V		12.4		ns
Turn-ON Rise Time		t _R	V _{DS} =-20V, V _{GS} =-10V,		9.2		
Turn-OFF Delay Time		t _{D(OFF)}	$R_L=1.35\Omega$, $R_{GEN}=3\Omega$		97.5		
Turn-OFF Fall-Time		t _F	(Note 1 ,2)		45.5		
SOURCE-DRAIN DIODE RATING	S AND CH	ARACTER	ISTICS				
Drain-Source Diode Forward Voltage		V_{SD}	I _S =-1A, V _{GS} =0V		0.71	1	V
Maximum Continuous Drain-Source Diode		Is				4.2	Α
Forward Current						4.2	
Body Diode Reverse Recovery Time		t _{RR}	I _F =-14A, dI/dt=100A/μs		35		ns
Body Diode Reverse Recovery Charge		Q _{RR}	I _F =-14A,dI/dt=100A/μs (Note 1)		35		nC

Note: 1. Pulse Test: Pulse width \leq 300 μ s, Duty cycle \leq 2%

2. Essentially independent of operating temperature

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